## Quantum transport evidence of Weyl fermions in a high-quality ferromagnetic perovskite oxide SrRuO<sub>3</sub> thin film

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Recently, Weyl fermions in ferromagnetic materials attract much attention because of their potential use in high-performance electronics, spintronics and quantum computing. SrRuO<sub>3</sub>, a 4*d* ferromagnetic metal with the perovskite structure, provides a promising opportunity to seek the existence of Weyl fermions in magnetic materials.<sup>[1]</sup> However, there is no experimental evidence of the Weyl fermions in SrRuO<sub>3</sub> due to difficulties in preparing high-quality specimens,<sup>[2]</sup> and such specimens are required to reveal intrinsic transport properties of the purported Weyl fermions.

In this presentation, we report the quantum transport evidence of the Weyl fermions in an epitaxial SrRuO<sub>3</sub> film with the best crystal quality ever reported. We grew 63-nm thick SrRuO<sub>3</sub> films on SrTiO<sub>3</sub> substrates by our recently developed machine-learning-assisted molecular beam epitaxy (ML-MBE) method,<sup>[3]</sup> and the residual resistivity ratio (RRR) [ $\rho$ (300 K)/ $\rho$ (T $\rightarrow$ 0 K)] of the films reached the world's best value of 84.3,<sup>[4]</sup> which allowed us to probe the intrinsic quantum transport properties of SrRuO<sub>3</sub>. The films were fabricated into Hall-bar devices.

We observed direct quantum transport evidence of Weyl fermions<sup>[5]</sup>: (i) unsaturated linear positive magnetoresistance (MR), (ii) chiral-anomaly-induced negative MR, (iii)  $\pi$  Berry phase accumulated along cyclotron orbits, (iv) light cyclotron masses, and (v) high quantum mobility of about 10000 cm<sup>2</sup>/Vs. Figures 1(a) and (b) show the Shubnikov-de Haas (SdH) oscillations and their Fourier transform spectra, respectively. The SdH oscillations above 2 K consist of two orbitals with frequencies of  $F_1$  (26 T) and  $F_2$  (44 T). In addition to signatures (i) and (ii) by independent MR measurements, we confirmed (iii)-(v) by detailed analyses of the SdH oscillation data using the Lifshitz-Kosevich (LK) theory.<sup>[6]</sup> Also, our first principles calculations found the Weyl nodes near the Fermi level which can reproduce our experimental results well.<sup>[4]</sup> Therefore, our experimental data and calculations establish SrRuO<sub>3</sub> as a magnetic Weyl semimetal.



Figure 1 (a) Oscilating component of the conductivity (SdH oscillation) of SrRuO<sub>3</sub> at 2 K. (b) Fourier transform spectra of SdH oscillations at 2 - 8 K. F<sub>1</sub> (= 26 T) and F<sub>2</sub> (= 44 T) are frequency peaks of Weyl fermions with 0.35*m*<sub>0</sub> and 0.58*m*<sub>0</sub>. respectively ( $m_0$ : free electron rest mass). Insets: temp. dependences of  $F_1$  and  $F_2$  peak amplitudes for the mass estimation using the LK theory.

**References** [1] Y. Chen *et al.*, *Phys. Rev. B* **88**, 125110 (2013). [2] G. Koster *et al.*, *Rev. Mod. Phys.* **84**, 253 (2012). [3] Y. K. Wakabayashi, *et al.*, *APL Mater.* **7**, 101114 (2019). [4] K. Takiguchi, Y. K. Wakabayashi, *et al.*, arXiv:2004.00810. [5] X. Huang *et al.*, *Phys. Rev. X* **5** 031023 (2015). [6] I. M. Lifshitz & A. M. Kosevich, Sov. Phys. JETP **2**, 636 (1956).